



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : HWANG et al. Confirmation No: 2598
Appl. No. : 10/022,349
Filed : December 20, 2001
Title : A SINGLE-CHIP STRUCTURE OF SILICON GERMANIUM
PHOTODETECTOR AND HIGH-SPEED TRANSISTOR

TC/A.U. : 2814
Examiner : D. Wille

Docket No.: : YAMA3001/REF
Customer No: : 23364

AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This is in response to the Official Action of August 8, 2003, in connection with the above-identified application. The period for response to this Official Action has been extended to expire on December 8, 2003 by the filing herewith of a Petition for a One Month Extension of Time and payment of the required fee.

Please amend the application as follows:

Amendments to the claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 7 of this paper.

